





PNP PRE-BIASED DUAL TRANSISTOR

Features

- **Epitaxial Planar Die Construction**
- Complementary NPN Types Available (DDC)
- **Built-In Biasing Resistors**
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

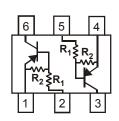
| | P/N | R1 (NOM) | R2 (NOM) | MARKING |
|---|----------|----------|----------|---------|
| | DDA122LH | 0.22KΩ | 10ΚΩ | P81 |
| | DDA142JH | 0.47ΚΩ | 10ΚΩ | P82 |
| ١ | DDA122TH | 0.22KΩ | OPEN | P83 |
| | DDA142TH | 0.47ΚΩ | OPEN | P84 |

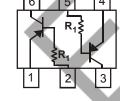
Mechanical Data

- Case: SOT-563
- Case Material: Molded Plastic; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208@3
- Terminal Connections: See Diagram
- Weight: 0.005 grams (Approximate)

SOT-563

SCHEMATIC DIAGRAM, TOP VIEW





R₁, R₂

R₁ Only

Note 5

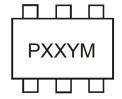
Ordering Information (Note 4)

| Device | Packaging | Shipping |
|------------|-----------|-------------------|
| DDA122LH-7 | SOT-563 | 3,000/Tape & Reel |
| DDA142JH-7 | SOT-563 | 3,000/Tape & Reel |
| DDA122TH-7 | SOT-563 | 3,000/Tape & Reel |
| DDA142TH-7 | SOT-563 | 3,000/Tape & Reel |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.
 Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed.

Marking Information



XXX = Product Type Marking Code YM = Date Code Marking Y = Year ex: I = 2021 M = Month ex: 9 = September

Date Code Key

| Year | 2021 | 2022 | 2023 | 202 | 4 20 | 25 20 | 026 | 2027 | 2028 | 2029 | 2030 | 2031 |
|-------|------|------|------|-----|------|----------|-----|------|-------|------|------|------|
| Code | I | J | K | L | N | / | N | 0 | Р | R | S | Т |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | j Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |



Maximum Ratings, R1, R2 Types (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Value | Unit |
|---|----------------------|-----------------------------------|----------------------|------|
| Supply Voltage | | Vcc | -50 | V |
| Input Voltage | DDA122LH DDA142JH | V _{IN} | +5 to -6 +5 to -6 | V |
| Input Voltage | DDA122TH DDA142TH | V _{EBO (MAX)} | -5 | V |
| Output Current | All | I _C | -100 | mA |
| Power Dissipation | | P _d | 150 | mW |
| Thermal Resistance, Junction to Ambient Air | | $R_{	hetaJA}$ | 833 | °C/W |
| Operating and Storage Temperature Range | | T _j , T _{STG} | -55 to +150 | °C |

Electrical Characteristics, R1, R2 Types (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|-----------------------------------|----------------------|---------------------|--------------|-----|--------------|---|--|
| Input Voltage | DDA122LH DDA142JH | V _{I(off)} | -0.3 -0.3 | _ | _ | ٧ | $V_{CC} = -5V$, $I_{O} = -100\mu A$ |
| | DDA122LH DDA142JH | $V_{l(on)}$ | _ | _ | -2.0 -2.0 | | $V_O = -0.3V$, $I_O = -20mA$ $V_O = -0.3V$, $I_O = -20mA$ |
| Output Voltage | | V _{O(on)} | _ | _ | -0.3V | ٧ | $I_{O}/I_{I} = -5$ mA/-0.25mA |
| Input Current DDA122LH DDA142JH | | I _I | | _ | -28 -13 | mA | V _I = -5V |
| Output Current | | I _{O(off)} | | _ | -0.5 | μΑ | V _{CC} = -50V, V _I = 0V |
| DC Current Gain DDA122LH DDA142JH | | Gı | 56 56 | _ | _ | _ | V _O = -5V, I _O = -10mA |
| Gain-Bandwidth Product* | f⊤ | _ | 200 | _ | MHz | $V_{CE} = -10V$, $I_{E} = -5mA$, $f = 100MHz$ | |

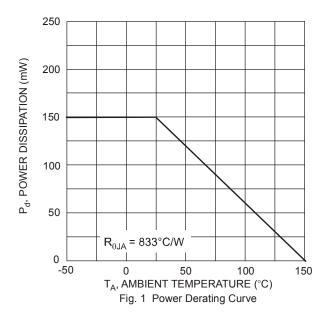
^{*} Transistor - For Reference Only

Electrical Characteristics, R1 Only (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|-------------------|----------------------|------------|------------|--------------|------------------------|--|
| Collector-Base Breakdown Voltage | BV_CBO | -50 | | _ | ٧ | I _C = -50μA | |
| Collector-Emitter Breakdown Voltage | BV _{CEO} | -40 | _ | _ | V | I _C = -1mA | |
| Emitter-Base Breakdown Voltage DDA122TH DDA142TH | | BV _{EBO} | -5 | _ | | ٧ | I _E = -50μA I _E = -50μA |
| Collector Cut-Off Current | | I _{CBO} | _ | _ | -0.5 | μΑ | V _{CB} = -50V |
| Emitter Cut-Off Current DDA122TH DDA142TH | | I _{EBO} | | | -0.5 -0.5 | μΑ | V _{EB} = -4V |
| Collector-Emitter Saturation Voltage | | V _{CE(sat)} | | | -0.3 | ٧ | I _C = -5mA, I _B = -0.25mA |
| DC Current Transfer Ratio DDA122TH DDA142TH | | h _{FE} | 100 100 | 250 250 | 600 600 | _ | I _C = -1mA, V _{CE} = -5V |
| Gain-Bandwidth Product* | | f⊤ | _ | 200 | | MHz | V _{CE} = -10V, I _E = 5mA, f = 100MHz |

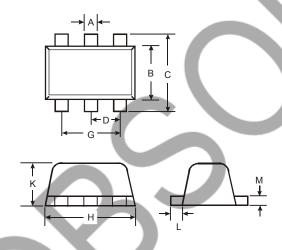
^{*} Transistor - For Reference Only





Package Outline Dimensions

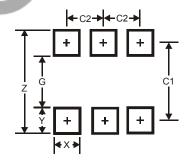
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



| SOT563 | | | | | | | | |
|----------------------|------|------|------|--|--|--|--|--|
| Dim | Min | Max | Тур | | | | | |
| Α | 0.15 | 0.30 | 0.20 | | | | | |
| В | 1.10 | 1.25 | 1.20 | | | | | |
| С | 1.55 | 1.70 | 1.60 | | | | | |
| D | - | - | 0.50 | | | | | |
| G | 0.90 | 1.10 | 1.00 | | | | | |
| Н | 1.50 | 1.70 | 1.60 | | | | | |
| K | 0.55 | 0.60 | 0.60 | | | | | |
| L | 0.10 | 0.30 | 0.20 | | | | | |
| M | 0.10 | 0.18 | 0.11 | | | | | |
| All Dimensions in mm | | | | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.2 |
| G | 1.2 |
| Х | 0.375 |
| Υ | 0.5 |
| C1 | 1.7 |
| C2 | 0.5 |



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